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Understanding Embedded - CPLDs (Complex Programmable Logic Devices)

Embedded - CPLDs, or Complex Programmable Logic Devices, are highly versatile digital logic devices used in electronic systems. These programmable components are designed to perform complex logical operations and can be customized for specific applications. Unlike fixed-function ICs, CPLDs offer the flexibility to reprogram their configuration, making them an ideal choice for various embedded systems. They consist of a set of logic gates and programmable interconnects, allowing designers to implement complex logic circuits without needing custom hardware.

Applications of Embedded - CPLDs

Details	
Product Status	Obsolete
Programmable Type	In System Programmable
Delay Time tpd(1) Max	10 ns
Voltage Supply - Internal	3V ~ 3.6V
Number of Logic Elements/Blocks	8
Number of Macrocells	128
Number of Gates	2500
Number of I/O	96
Operating Temperature	0°C ~ 70°C (TA)
Mounting Type	Surface Mount
Package / Case	144-LQFP
Supplier Device Package	144-TQFP (20x20)
Purchase URL	https://www.e-xfl.com/product-detail/intel/epm3128atc144-10n

Email: info@E-XFL.COM

Address: Room A, 16/F, Full Win Commercial Centre, 573 Nathan Road, Mongkok, Hong Kong

...and More Features

- PCI compatible
- Bus-friendly architecture including programmable slew-rate control
- Open–drain output option
- Programmable macrocell flipflops with individual clear, preset, clock, and clock enable controls
- Programmable power–saving mode for a power reduction of over 50% in each macrocell
- Configurable expander product–term distribution, allowing up to 32 product terms per macrocell
- Programmable security bit for protection of proprietary designs
- Enhanced architectural features, including:
 - 6 or 10 pin– or logic–driven output enable signals
 - Two global clock signals with optional inversion
 - Enhanced interconnect resources for improved routability
 - Programmable output slew–rate control
- Software design support and automatic place—and—route provided by Altera's development systems for Windows—based PCs and Sun SPARCstations, and HP 9000 Series 700/800 workstations
- Additional design entry and simulation support provided by EDIF 2 0 0 and 3 0 0 netlist files, library of parameterized modules (LPM), Verilog HDL, VHDL, and other interfaces to popular EDA tools from third–party manufacturers such as Cadence, Exemplar Logic, Mentor Graphics, OrCAD, Synopsys, Synplicity, and VeriBest
- Programming support with the Altera master programming unit (MPU), MasterBlasterTM communications cable, ByteBlasterMVTM parallel port download cable, BitBlasterTM serial download cable as well as programming hardware from third–party manufacturers and any in–circuit tester that supports JamTM Standard Test and Programming Language (STAPL) Files (.jam), Jam STAPL Byte-Code Files (.jbc), or Serial Vector Format Files (.svf)

General Description

MAX 3000A devices are low–cost, high–performance devices based on the Altera MAX architecture. Fabricated with advanced CMOS technology, the EEPROM–based MAX 3000A devices operate with a 3.3-V supply voltage and provide 600 to 10,000 usable gates, ISP, pin-to-pin delays as fast as 4.5 ns, and counter speeds of up to 227.3 MHz. MAX 3000A devices in the -4, -5, -6, -7, and -10 speed grades are compatible with the timing requirements of the PCI Special Interest Group (PCI SIG) *PCI Local Bus Specification, Revision 2.2.* See Table 2.

Table 2. MAX	Table 2. MAX 3000A Speed Grades										
Device			Speed Grade	1							
	-4	-5	-6	-7	-10						
EPM3032A	✓			✓	✓						
EPM3064A	✓			✓	✓						
EPM3128A		✓		✓	✓						
EPM3256A				✓	✓						
EPM3512A				✓	✓						

The MAX 3000A architecture supports 100% transistor-to-transistor logic (TTL) emulation and high–density small-scale integration (SSI), medium-scale integration (MSI), and large-scale integration (LSI) logic functions. The MAX 3000A architecture easily integrates multiple devices ranging from PALs, GALs, and 22V10s to MACH and pLSI devices. MAX 3000A devices are available in a wide range of packages, including PLCC, PQFP, and TQFP packages. See Table 3.

Table 3. MAX	3000A Max	Note (1))			
Device	44-Pin PLCC	44-Pin TQFP	100-Pin TQFP	144-Pin TQFP	208-Pin PQFP	256-Pin FineLine BGA
EPM3032A	34	34				
EPM3064A	34	34	66			
EPM3128A			80	96		98
EPM3256A				116	158	161
EPM3512A					172	208

Note:

(1) When the IEEE Std. 1149.1 (JTAG) interface is used for in–system programming or boundary–scan testing, four I/O pins become JTAG pins.

MAX 3000A devices use CMOS EEPROM cells to implement logic functions. The user–configurable MAX 3000A architecture accommodates a variety of independent combinatorial and sequential logic functions. The devices can be reprogrammed for quick and efficient iterations during design development and debugging cycles, and can be programmed and erased up to 100 times.

MAX 3000A devices contain 32 to 512 macrocells, combined into groups of 16 macrocells called logic array blocks (LABs). Each macrocell has a programmable—AND/fixed—OR array and a configurable register with independently programmable clock, clock enable, clear, and preset functions. To build complex logic functions, each macrocell can be supplemented with shareable expander and high–speed parallel expander product terms to provide up to 32 product terms per macrocell.

MAX 3000A devices provide programmable speed/power optimization. Speed-critical portions of a design can run at high speed/full power, while the remaining portions run at reduced speed/low power. This speed/power optimization feature enables the designer to configure one or more macrocells to operate at 50% or lower power while adding only a nominal timing delay. MAX 3000A devices also provide an option that reduces the slew rate of the output buffers, minimizing noise transients when non-speed-critical signals are switching. The output drivers of all MAX 3000A devices can be set for 2.5 V or 3.3 V, and all input pins are 2.5–V, 3.3–V, and 5.0-V tolerant, allowing MAX 3000A devices to be used in mixed-voltage systems.

MAX 3000A devices are supported by Altera development systems, which are integrated packages that offer schematic, text—including VHDL, Verilog HDL, and the Altera Hardware Description Language (AHDL)—and waveform design entry, compilation and logic synthesis, simulation and timing analysis, and device programming. The software provides EDIF 2 0 0 and 3 0 0, LPM, VHDL, Verilog HDL, and other interfaces for additional design entry and simulation support from other industry–standard PC– and UNIX–workstation–based EDA tools. The software runs on Windows–based PCs, as well as Sun SPARCstation, and HP 9000 Series 700/800 workstations.



For more information on development tools, see the MAX+PLUS II Programmable Logic Development System & Software Data Sheet and the Quartus Programmable Logic Development System & Software Data Sheet.

Functional Description

The MAX 3000A architecture includes the following elements:

- Logic array blocks (LABs)
- Macrocells
- Expander product terms (shareable and parallel)
- Programmable interconnect array (PIA)
- I/O control blocks

The MAX 3000A architecture includes four dedicated inputs that can be used as general–purpose inputs or as high–speed, global control signals (clock, clear, and two output enable signals) for each macrocell and I/O pin. Figure 1 shows the architecture of MAX 3000A devices.

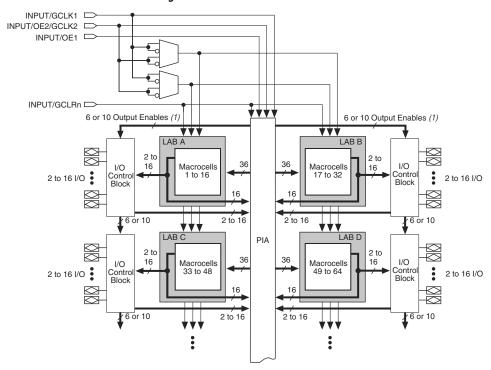


Figure 1. MAX 3000A Device Block Diagram

Note:

(1) EPM3032A, EPM3064A, EPM3128A, and EPM3256A devices have six output enables. EPM3512A devices have 10 output enables.

Logic Array Blocks

The MAX 3000A device architecture is based on the linking of high–performance LABs. LABs consist of 16–macrocell arrays, as shown in Figure 1. Multiple LABs are linked together via the PIA, a global bus that is fed by all dedicated input pins, I/O pins, and macrocells.

Each LAB is fed by the following signals:

- 36 signals from the PIA that are used for general logic inputs
- Global controls that are used for secondary register functions

Parallel Expanders

Parallel expanders are unused product terms that can be allocated to a neighboring macrocell to implement fast, complex logic functions. Parallel expanders allow up to 20 product terms to directly feed the macrocell OR logic, with five product terms provided by the macrocell and 15 parallel expanders provided by neighboring macrocells in the LAB.

The Altera development system compiler can automatically allocate up to three sets of up to five parallel expanders to the macrocells that require additional product terms. Each set of five parallel expanders incurs a small, incremental timing delay (t_{PEXP}). For example, if a macrocell requires 14 product terms, the compiler uses the five dedicated product terms within the macrocell and allocates two sets of parallel expanders; the first set includes five product terms, and the second set includes four product terms, increasing the total delay by $2 \times t_{PEXP}$.

Two groups of eight macrocells within each LAB (e.g., macrocells 1 through 8 and 9 through 16) form two chains to lend or borrow parallel expanders. A macrocell borrows parallel expanders from lower–numbered macrocells. For example, macrocell 8 can borrow parallel expanders from macrocell 7, from macrocells 7 and 6, or from macrocells 7, 6, and 5. Within each group of eight, the lowest–numbered macrocell can only lend parallel expanders and the highest–numbered macrocell can only borrow them. Figure 4 shows how parallel expanders can be borrowed from a neighboring macrocell.

In-System Programmability

MAX 3000A devices can be programmed in–system via an industry–standard four–pin IEEE Std. 1149.1-1990 (JTAG) interface. In-system programmability (ISP) offers quick, efficient iterations during design development and debugging cycles. The MAX 3000A architecture internally generates the high programming voltages required to program its EEPROM cells, allowing in–system programming with only a single 3.3–V power supply. During in–system programming, the I/O pins are tri–stated and weakly pulled–up to eliminate board conflicts. The pull–up value is nominally 50 k Ω

MAX 3000A devices have an enhanced ISP algorithm for faster programming. These devices also offer an ISP_Done bit that ensures safe operation when in–system programming is interrupted. This ISP_Done bit, which is the last bit programmed, prevents all I/O pins from driving until the bit is programmed.

ISP simplifies the manufacturing flow by allowing devices to be mounted on a printed circuit board (PCB) with standard pick—and—place equipment before they are programmed. MAX 3000A devices can be programmed by downloading the information via in—circuit testers, embedded processors, the MasterBlaster communications cable, the ByteBlasterMV parallel port download cable, and the BitBlaster serial download cable. Programming the devices after they are placed on the board eliminates lead damage on high—pin—count packages (e.g., QFP packages) due to device handling. MAX 3000A devices can be reprogrammed after a system has already shipped to the field. For example, product upgrades can be performed in the field via software or modem.

The Jam STAPL programming and test language can be used to program MAX 3000A devices with in–circuit testers, PCs, or embedded processors.



For more information on using the Jam STAPL programming and test language, see *Application Note 88* (Using the Jam Language for ISP & ICR via an Embedded Processor), *Application Note 122* (Using Jam STAPL for ISP & ICR via an Embedded Processor) and AN 111 (Embedded Programming Using the 8051 and Jam Byte-Code).

The ISP circuitry in MAX 3000A devices is compliant with the IEEE Std. 1532 specification. The IEEE Std. 1532 is a standard developed to allow concurrent ISP between multiple PLD vendors.

By combining the pulse and shift times for each of the programming stages, the program or verify time can be derived as a function of the TCK frequency, the number of devices, and specific target device(s). Because different ISP-capable devices have a different number of EEPROM cells, both the total fixed and total variable times are unique for a single device.

Programming a Single MAX 3000A Device

The time required to program a single MAX 3000A device in-system can be calculated from the following formula:

$$t_{PROG} = t_{PPULSE} + \frac{Cycle_{PTCK}}{f_{TCK}}$$

where: $t_{PROG} = Programming time$ $t_{PPULSE} = Sum of the fixed times to erase, program, and$

verify the EEPROM cells

 $Cycle_{PTCK}$ = Number of TCK cycles to program a device

= TCK frequency

The ISP times for a stand-alone verification of a single MAX 3000A device can be calculated from the following formula:

$$t_{VER} = t_{VPULSE} + \frac{Cycle_{VTCK}}{f_{TCK}}$$

where: t_{VER} = Verify time t_{VPULSE} = Sum of the fixed times to verify the EEPROM cells $Cycle_{VTCK}$ = Number of TCK cycles to verify a device

The instruction register length of MAX 3000A devices is 10 bits. The IDCODE and USERCODE register length is 32 bits. Tables 8 and 9 show the boundary–scan register length and device IDCODE information for MAX 3000A devices.

Table 8. MAX 3000A Boundary-Sc	an Register Length
Device	Boundary–Scan Register Length
EPM3032A	96
EPM3064A	192
EPM3128A	288
EPM3256A	480
EPM3512A	624

Table 9. 32-	Table 9. 32–Bit MAX 3000A Device IDCODE Value Note (1)												
Device		IDCODE (32 I	oits)										
	Version (4 Bits) Part Number (16 Bits) Manufacturer' Identity (11 Bit												
EPM3032A	0001	0111 0000 0011 0010	00001101110	1									
EPM3064A	0001	0111 0000 0110 0100	00001101110	1									
EPM3128A	0001	0111 0001 0010 1000	00001101110	1									
EPM3256A	0001	0111 0010 0101 0110	00001101110	1									
EPM3512A	0001	0111 0101 0001 0010	00001101110	1									

Notes:

- (1) The most significant bit (MSB) is on the left.
- (2) The least significant bit (LSB) for all JTAG IDCODEs is 1.



See Application Note 39 (IEEE 1149.1 (JTAG) Boundary–Scan Testing in Altera Devices) for more information on JTAG BST.

 $V_{CCINT} = 3.3 V$

V_{CCIO} = 2.5 V

Temperature = 25 °C

150 I_{OL} 100 Typical I_O $V_{CCINT} = 3.3 V$ Output $V_{CCIO} = 3.3 V$ Current (mA) Temperature = 25 °C 50 I_{OH} 2 V_O Output Voltage (V) 2.5 V 150 I_{OL}

Figure 9. Output Drive Characteristics of MAX 3000A Devices

3.3 V

Power Sequencing & Hot-Socketing

Because MAX 3000A devices can be used in a mixed–voltage environment, they have been designed specifically to tolerate any possible power–up sequence. The $\rm V_{CCIO}$ and $\rm V_{CCINT}$ power planes can be powered in any order.

V_O Output Voltage (V)

Signals can be driven into MAX 3000A devices before and during power-up without damaging the device. In addition, MAX 3000A devices do not drive out during power-up. Once operating conditions are reached, MAX 3000A devices operate as specified by the user.

Altera Corporation 25

100

50

Typical I_O

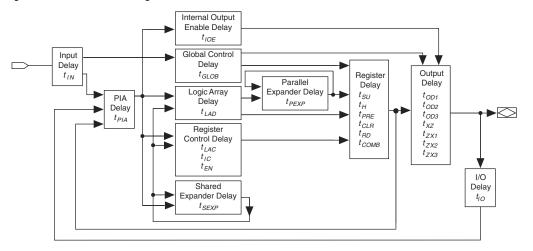
Current (mA)

Output

Timing Model

MAX 3000A device timing can be analyzed with the Altera software, with a variety of popular industry–standard EDA simulators and timing analyzers, or with the timing model shown in Figure 10. MAX 3000A devices have predictable internal delays that enable the designer to determine the worst–case timing of any design. The software provides timing simulation, point–to–point delay prediction, and detailed timing analysis for device–wide performance evaluation.

Figure 10. MAX 3000A Timing Model



The timing characteristics of any signal path can be derived from the timing model and parameters of a particular device. External timing parameters, which represent pin–to–pin timing delays, can be calculated as the sum of internal parameters. Figure 11 shows the timing relationship between internal and external delay parameters.

Symbol	Parameter	Conditions			Speed	Grade			Unit
			_	-4		-7	-10		
			Min	Max	Min	Max	Min	Max	
t _{IN}	Input pad and buffer delay			0.6		1.1		1.4	ns
t _{IO}	I/O input pad and buffer delay			0.6		1.1		1.4	ns
t _{SEXP}	Shared expander delay			1.8		3.0		3.9	ns
t _{PEXP}	Parallel expander delay			0.4		0.7		0.9	ns
t_{LAD}	Logic array delay			1.5		2.5		3.2	ns
t _{LAC}	Logic control array delay			0.6		1.0		1.2	ns
t _{IOE}	Internal output enable delay			0.0		0.0		0.0	ns
t _{OD1}	Output buffer and pad delay, slow slew rate = off V _{CCIO} = 3.3 V	C1 = 35 pF		0.8		1.3		1.8	ns
t _{OD2}	Output buffer and pad delay, slow slew rate = off V _{CCIO} = 2.5 V	C1 = 35 pF		1.3		1.8		2.3	ns
t _{OD3}	Output buffer and pad delay, slow slew rate = on V _{CCIO} = 2.5 V or 3.3 V	C1 = 35 pF		5.8		6.3		6.8	ns
t _{ZX1}	Output buffer enable delay, slow slew rate = off $V_{CCIO} = 3.3 \text{ V}$	C1 = 35 pF		4.0		4.0		5.0	ns
t _{ZX2}	Output buffer enable delay, slow slew rate = off $V_{CCIO} = 2.5 \text{ V}$	C1 = 35 pF		4.5		4.5		5.5	ns
t _{ZX3}	Output buffer enable delay, slow slew rate = on V _{CCIO} = 2.5 V or 3.3 V	C1 = 35 pF		9.0		9.0		10.0	ns
t_{XZ}	Output buffer disable delay	C1 = 5 pF		4.0		4.0		5.0	ns
t _{SU}	Register setup time		1.3		2.0		2.9		ns
t _H	Register hold time		0.6		1.0		1.3		ns
t _{RD}	Register delay			0.7		1.2		1.6	ns
t _{COMB}	Combinatorial delay			0.6		0.9		1.3	ns
t _{IC}	Array clock delay			1.2		1.9		2.5	ns
t_{EN}	Register enable time			0.6		1.0		1.2	ns
t _{GLOB}	Global control delay			1.0		1.5		2.2	ns
t _{PRE}	Register preset time			1.3		2.1		2.9	ns

Table 19	Table 19. EPM3064A Internal Timing Parameters (Part 2 of 2) Note (1)											
Symbol	Parameter	Conditions			Speed	Grade			Unit			
			_	4	-7		-10					
			Min	Max	Min	Max	Min	Max				
t _{CLR}	Register clear time			1.3		2.1		2.9	ns			
t _{PIA}	PIA delay	(2)		1.0		1.7		2.3	ns			
t_{LPA}	Low-power adder	(5)		3.5		4.0		5.0	ns			

Table 2	D. EPM3128A External 1	iming Param	eters	Note (1)					
Symbol	Parameter	Conditions			Speed	Grade			Unit
			-	5	_	7		10	
			Min	Max	Min	Max	Min	Max	
t _{PD1}	Input to non– registered output	C1 = 35 pF (2)		5.0		7.5		10	ns
t _{PD2}	I/O input to non– registered output	C1 = 35 pF (2)		5.0		7.5		10	ns
t _{SU}	Global clock setup time	(2)	3.3		4.9		6.6		ns
t _H	Global clock hold time	(2)	0.0		0.0		0.0		ns
t _{CO1}	Global clock to output delay	C1 = 35 pF	1.0	3.4	1.0	5.0	1.0	6.6	ns
t _{CH}	Global clock high time		2.0		3.0		4.0		ns
t _{CL}	Global clock low time		2.0		3.0		4.0		ns
t _{ASU}	Array clock setup time	(2)	1.8		2.8		3.8		ns
t _{AH}	Array clock hold time	(2)	0.2		0.3		0.4		ns
t _{ACO1}	Array clock to output delay	C1 = 35 pF (2)	1.0	4.9	1.0	7.1	1.0	9.4	ns
t _{ACH}	Array clock high time		2.0		3.0		4.0		ns
t _{ACL}	Array clock low time		2.0		3.0		4.0		ns
t _{CPPW}	Minimum pulse width for clear and preset	(3)	2.0		3.0		4.0		ns
t _{CNT}	Minimum global clock period	(2)		5.2		7.7		10.2	ns
f _{CNT}	Maximum internal global clock frequency	(2), (4)	192.3		129.9		98.0		MHz
t _{ACNT}	Minimum array clock period	(2)		5.2		7.7		10.2	ns

Table 20	Table 20. EPM3128A External Timing Parameters Note (1)										
Symbol	Parameter	Conditions			Speed	Grade			Unit		
			-	-5 -7 -10			10				
			Min	Max	Min	Max	Min	Max			
f _{ACNT}	Maximum internal array clock frequency	(2), (4)	192.3		129.9		98.0		MHz		

Table 2	1. EPM3128A Internal Timing	g Parameters (I	Part 1 of	2) N	ote (1)				
Symbol	Parameter	Conditions			Speed	Grade			Unit
			_	·5	-	-7		10	
			Min	Max	Min	Max	Min	Max	
t _{IN}	Input pad and buffer delay			0.7		1.0		1.4	ns
t _{IO}	I/O input pad and buffer delay			0.7		1.0		1.4	ns
t _{SEXP}	Shared expander delay			2.0		2.9		3.8	ns
t _{PEXP}	Parallel expander delay			0.4		0.7		0.9	ns
t_{LAD}	Logic array delay			1.6		2.4		3.1	ns
t_{LAC}	Logic control array delay			0.7		1.0		1.3	ns
t _{IOE}	Internal output enable delay			0.0		0.0		0.0	ns
t _{OD1}	Output buffer and pad delay, slow slew rate = off $V_{CCIO} = 3.3 \text{ V}$	C1 = 35 pF		0.8		1.2		1.6	ns
t _{OD2}	Output buffer and pad delay, slow slew rate = off V _{CCIO} = 2.5 V	C1 = 35 pF		1.3		1.7		2.1	ns
t _{OD3}	Output buffer and pad delay, slow slew rate = on V _{CCIO} = 2.5 V or 3.3 V	C1 = 35 pF		5.8		6.2		6.6	ns
t _{ZX1}	Output buffer enable delay, slow slew rate = off $V_{CCIO} = 3.3 \text{ V}$	C1 = 35 pF		4.0		4.0		5.0	ns
t _{ZX2}	Output buffer enable delay, slow slew rate = off V _{CCIO} = 2.5 V	C1 = 35 pF		4.5		4.5		5.5	ns
t _{ZX3}	Output buffer enable delay, slow slew rate = on V _{CCIO} = 2.5 V or 3.3 V	C1 = 35 pF		9.0		9.0		10.0	ns
t_{XZ}	Output buffer disable delay	C1 = 5 pF		4.0		4.0		5.0	ns

Table 21	Table 21. EPM3128A Internal Timing Parameters (Part 2 of 2) Note (1)											
Symbol	Parameter	Conditions	Speed Grade									
			_	- 5		-7		10				
			Min	Max	Min	Max	Min	Max				
t _{SU}	Register setup time		1.4		2.1		2.9		ns			
t _H	Register hold time		0.6		1.0		1.3		ns			
t _{RD}	Register delay			0.8		1.2		1.6	ns			
t _{COMB}	Combinatorial delay			0.5		0.9		1.3	ns			
t _{IC}	Array clock delay			1.2		1.7		2.2	ns			
t _{EN}	Register enable time			0.7		1.0		1.3	ns			
t _{GLOB}	Global control delay			1.1		1.6		2.0	ns			
t _{PRE}	Register preset time			1.4		2.0		2.7	ns			
t _{CLR}	Register clear time			1.4		2.0		2.7	ns			
t _{PIA}	PIA delay	(2)		1.4		2.0		2.6	ns			
t_{LPA}	Low-power adder	(5)		4.0		4.0		5.0	ns			

Table 22.	EPM3256A External Timing	Parameters	Note (1)				
Symbol	Parameter	Conditions		Speed	Grade		Unit
			=	-7		10	
			Min	Max	Min	Max	
t _{PD1}	Input to non–registered output	C1 = 35 pF (2)		7.5		10	ns
t _{PD2}	I/O input to non–registered output	C1 = 35 pF (2)		7.5		10	ns
t _{SU}	Global clock setup time	(2)	5.2		6.9		ns
t _H	Global clock hold time	(2)	0.0		0.0		ns
t _{CO1}	Global clock to output delay	C1 = 35 pF	1.0	4.8	1.0	6.4	ns
t _{CH}	Global clock high time		3.0		4.0		ns
t _{CL}	Global clock low time		3.0		4.0		ns
t _{ASU}	Array clock setup time	(2)	2.7		3.6		ns
t _{AH}	Array clock hold time	(2)	0.3		0.5		ns
t _{ACO1}	Array clock to output delay	C1 = 35 pF (2)	1.0	7.3	1.0	9.7	ns
t _{ACH}	Array clock high time		3.0		4.0		ns
t _{ACL}	Array clock low time		3.0		4.0		ns
t _{CPPW}	Minimum pulse width for clear and preset	(3)	3.0		4.0		ns

Table 23. EPM3256A Internal Timing Parameters (Part 2 of 2) Note (1)							
Symbol	Parameter	Conditions	Speed Grade			Unit	
			-7		-10		1
			Min	Max	Min	Max	
t_{ZX3}	Output buffer enable delay, slow slew rate = on V _{CCIO} = 2.5 V or 3.3 V	C1 = 35 pF		9.0		10.0	ns
t _{XZ}	Output buffer disable delay	C1 = 5 pF		4.0		5.0	ns
t _{SU}	Register setup time		2.1		2.9		ns
t_H	Register hold time		0.9		1.2		ns
t _{RD}	Register delay			1.2		1.6	ns
t _{COMB}	Combinatorial delay			0.8		1.2	ns
t _{IC}	Array clock delay			1.6		2.1	ns
t _{EN}	Register enable time			1.0		1.3	ns
t _{GLOB}	Global control delay			1.5		2.0	ns
t _{PRE}	Register preset time			2.3		3.0	ns
t _{CLR}	Register clear time			2.3		3.0	ns
t _{PIA}	PIA delay	(2)		2.4		3.2	ns
t_{LPA}	Low-power adder	(5)		4.0		5.0	ns

Table 24. EPM3512A External Timing Parameters Note (1)							
Symbol	Parameter	Conditions	Speed Grade				Unit
			-7		-10		
			Min	Max	Min	Max	
t _{PD1}	Input to non-registered output	C1 = 35 pF (2)		7.5		10.0	ns
t _{PD2}	I/O input to non-registered output	C1 = 35 pF (2)		7.5		10.0	ns
t _{SU}	Global clock setup time	(2)	5.6		7.6		ns
t _H	Global clock hold time	(2)	0.0		0.0		ns
t _{FSU}	Global clock setup time of fast input		3.0		3.0		ns
t _{FH}	Global clock hold time of fast input		0.0		0.0		ns
t _{CO1}	Global clock to output delay	C1 = 35 pF	1.0	4.7	1.0	6.3	ns
t _{CH}	Global clock high time		3.0		4.0		ns
t _{CL}	Global clock low time		3.0		4.0		ns
t _{ASU}	Array clock setup time	(2)	2.5		3.5		ns

Symbol	Parameter	Conditions		Unit			
			-7		-10		
			Min	Max	Min	Max	
t _{OD3}	Output buffer and pad delay, slow slew rate = on $V_{CCIO} = 2.5 \text{ V or } 3.3 \text{ V}$	C1 = 35 pF		6.0		6.5	ns
t _{ZX1}	Output buffer enable delay, slow slew rate = off $V_{CCIO} = 3.3 \text{ V}$	C1 = 35 pF		4.0		5.0	ns
t _{ZX2}	Output buffer enable delay, slow slew rate = off V _{CCIO} = 2.5 V	C1 = 35 pF		4.5		5.5	ns
t _{ZX3}	Output buffer enable delay, slow slew rate = on $V_{\rm CCIO} = 3.3 \ { m V}$	C1 = 35 pF		9.0		10.0	ns
t_{XZ}	Output buffer disable delay	C1 = 5 pF		4.0		5.0	ns
t _{SU}	Register setup time		2.1		3.0		ns
t _H	Register hold time		0.6		0.8		ns
t _{FSU}	Register setup time of fast input		1.6		1.6		ns
t _{FH}	Register hold time of fast input		1.4		1.4		ns
t _{RD}	Register delay			1.3		1.7	ns
t _{COMB}	Combinatorial delay			0.6		0.8	ns
t _{IC}	Array clock delay			1.8		2.3	ns
t _{EN}	Register enable time			1.0		1.3	ns
t _{GLOB}	Global control delay			1.7		2.2	ns
t _{PRE}	Register preset time			1.0		1.4	ns
t _{CLR}	Register clear time			1.0		1.4	ns
t _{PIA}	PIA delay	(2)		3.0		4.0	ns
t _{LPA}	Low-power adder	(5)		4.5		5.0	ns

Notes to tables:

- (1) These values are specified under the recommended operating conditions, as shown in Table 13 on page 23. See Figure 11 on page 27 for more information on switching waveforms.
- (2) These values are specified for a PIA fan-out of one LAB (16 macrocells). For each additional LAB fan-out in these devices, add an additional 0.1 ns to the PIA timing value.
- (3) This minimum pulse width for preset and clear applies for both global clear and array controls. The t_{LPA} parameter must be added to this minimum width if the clear or reset signal incorporates the t_{LAD} parameter into the signal path.
- (4) These parameters are measured with a 16-bit loadable, enabled, up/down counter programmed into each LAB.
- (5) The t_{LPA} parameter must be added to the t_{LAD} , t_{LAC} , t_{IC} , t_{EN} , t_{SEXP} , $\mathbf{t_{ACL}}$, and $\mathbf{t_{CPPW}}$ parameters for macrocells running in low–power mode.

Power Consumption

Supply power (P) versus frequency (f_{MAX}, in MHz) for MAX 3000A devices is calculated with the following equation:

$$P = P_{INT} + P_{IO} = I_{CCINT} \times V_{CC} + P_{IO}$$

The $P_{\rm IO}$ value, which depends on the device output load characteristics and switching frequency, can be calculated using the guidelines given in *Application Note 74 (Evaluating Power for Altera Devices)*.

The I_{CCINT} value depends on the switching frequency and the application logic. The I_{CCINT} value is calculated with the following equation:

 $I_{CCINT} =$

$$(A \times MC_{TON}) + [B \times (MC_{DEV} - MC_{TON})] + (C \times MC_{USED} \times f_{MAX} \times tog_{LC})$$

The parameters in the I_{CCINT} equation are:

 MC_{TON} = Number of macrocells with the Turbo BitTM option turned

on, as reported in the Quartus II or MAX+PLUS II Report

File (.rpt)

 MC_{DEV} = Number of macrocells in the device

MC_{USED} = Total number of macrocells in the design, as reported in

the RPT File

 f_{MAX} = Highest clock frequency to the device

tog_{LC} = Average percentage of logic cells toggling at each clock

(typically 12.5%)

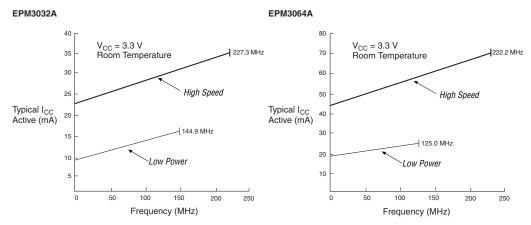
A, B, C = Constants (shown in Table 26)

Table 26. MAX 3000A I _{CC} Equation Constants						
Device	A	В	C			
EPM3032A	0.71	0.30	0.014			
EPM3064A	0.71	0.30	0.014			
EPM3128A	0.71	0.30	0.014			
EPM3256A	0.71	0.30	0.014			
EPM3512A	0.71	0.30	0.014			

The I_{CCINT} calculation provides an I_{CC} estimate based on typical conditions using a pattern of a 16–bit, loadable, enabled, up/down counter in each LAB with no output load. Actual I_{CC} should be verified during operation because this measurement is sensitive to the actual pattern in the device and the environmental operating conditions.

Figures 12 and 13 show the typical supply current versus frequency for MAX 3000A devices.

Figure 12. I_{CC} vs. Frequency for MAX 3000A Devices



EPM3128A

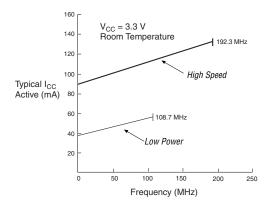
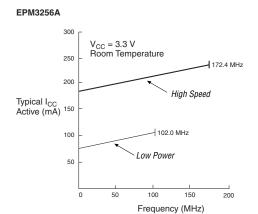
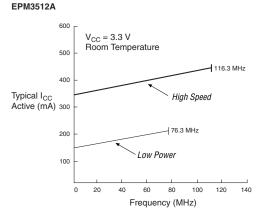


Figure 13. I_{CC} vs. Frequency for MAX 3000A Devices





Device Pin-Outs

See the Altera web site (http://www.altera.com) or the *Altera Digital Library* for pin–out information.

Figures 14 through 18 show the package pin-out diagrams for MAX 3000A devices.

Figure 14. 44-Pin PLCC/TQFP Package Pin-Out Diagram

Package outlines not drawn to scale.

